EX.

	Application No.	Applicant(s)
Notice of Allowability	10/716,878	CROSS ET AL.
	Examiner	Art Unit
	Hoai ∨. Pham	2814
The MAILING DATE of this communication appears on the cover sheet with the correspondence address All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS. This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308.		
1. This communication is responsive to <u>12/14/2005</u> .		
2. The allowed claim(s) is/are <u>1-4,8 and 9</u> .		
3.		
Attachment(s)  1. Notice of References Cited (PTO-892)  2. Notice of Draftperson's Patent Drawing Review (PTO-948)  3. Information Disclosure Statements (PTO-1449 or PTO/SB/O Paper No./Mail Date  4. Examiner's Comment Regarding Requirement for Deposit of Biological Material	6. ☐ Interview Summary Paper No./Mail Da 08), 7. ☒ Examiner's Amendr	te

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### **DETAILED ACTION**

#### Examiner's amendment

- 1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MÜST be submitted no later than the payment of the issue fee.
- 2. This application is in condition for allowance except for the presence of claims 5-7 and 10-13 non-elected without traverse. Accordingly, claims 5-7 and 10-13 been cancelled.
- 3. The application has been amended as follows:

# In the claims:

Cancel claims 5-7 and 10-13.

## In the specification:

Change the title to: --A SEMICONDUCTOR DEVICE HAVING A STRESS LAYER FOR APPLYING TENSILE OR COMPRESSIVE STRESS TO THE FERROELECTRIC FILM--.

## Allowable Subject Matter

- 4. Claims 1-4, 8 and 9 are allowed.
- 5. The following is an examiner's statement of reasons for allowance: the prior of record fails to disclose the combination of a semiconductor device structure recited in the base claim 1, including the combination of the structure of: a stress application layer

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which actively applies tensile or compressive stress to the ferroelectric film of the ferroelectric capacitor by deforming the substrate.

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Hoai v. Pham whose telephone number is 571-272-1715. The examiner can normally be reached on M-F.

- 7. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael M. Fahmy can be reached on 571-272-1705. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.
- 8. Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

HOAI PHAM PRIMARY EXAMINER